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December 2013

### FQB8N60C / FQI8N60C

### N-Channel QFET® MOSFET

600 V, 7.5 A, 1.2 Ω

### Description

This N-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state • Low Gate Charge (Typ. 28 nC) resistance, and to provide superior switching performance • Low Crss (Typ. 12 pF) and high avalanche energy strength. These devices are suitable for switched mode power supplies, active power • 100% Avalanche Tested factor correction (PFC), and electronic lamp ballasts.

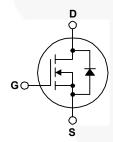
#### **Features**

- 7.5 A, 600 V,  $R_{DS(on)}$  = 1.2  $\Omega$  (Max.) @  $V_{GS}$  = 10 V,  $I_D = 3.75 A$

- · RoHS Compliant







### Absolute Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted.

Symbol	Parameter	FQB8N60CTM / FQI8N60CTU	Unit
V <sub>DSS</sub>	Drain-Source Voltage	600	V
I <sub>D</sub>	Drain Current - Continuous (T <sub>C</sub> = 25°C)	7.5	Α
	- Continuous (T <sub>C</sub> = 100°C)	4.6	Α
I <sub>DM</sub>	Drain Current - Pulsed (Not	1) 30	Α
V <sub>GSS</sub>	Gate-Source Voltage	± 30	V
E <sub>AS</sub>	Single Pulsed Avalanche Energy (Not	2) 230	mJ
I <sub>AR</sub>	Avalanche Current (Not	1) 7.5	Α
E <sub>AR</sub>	Repetitive Avalanche Energy (Not	1) 14.7	mJ
dv/dt	Peak Diode Recovery dv/dt (Not	3) 4.5	V/ns
	Power Dissipation (T <sub>A</sub> = 25°C)*	3.13	W
$P_D$	Power Dissipation (T <sub>C</sub> = 25°C)	147	W
	- Derate above 25°C	1.18	W/°C
$T_J$ , $T_{STG}$	Operating and Storage Temperature Range	-55 to +150	°C
T <sub>L</sub>	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds.	300	°C

### **Thermal Characteristics**

Symbol	Parameter	FQB8N60CTM / FQI8N60CTU	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	0.85	
В	Thermal Resistance, Junction to Ambient (Minimum Pad of 2-oz Copper), Max.	62.5	°C/W
R <sub>θJA</sub> Thermal Resistance, Junction to Ambient (*1 in² Pad of 2-oz Copper), Max.		40	

### **Package Marking and Ordering Information**

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FQB8N60CTM	FQB8N60C	D <sup>2</sup> -PAK	Tape and Reel	330 mm	24 mm	800 units
FQI8N60CTU	FQI8N60C	I <sup>2</sup> -PAK	Tube	N/A	N/A	50 units

### **Electrical Characteristics**

T<sub>C</sub> = 25°C unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Cha	aracteristics					
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	600			V
ΔBV <sub>DSS</sub> / ΔT <sub>J</sub>	Breakdown Voltage Temperature Coefficient	$I_D = 250 \mu A$ , Referenced to 25°C		0.7		V/°C
I <sub>DSS</sub>	Zero Ceta Valta de Ducia Comunit	V <sub>DS</sub> = 600 V, V <sub>GS</sub> = 0 V			1	μΑ
	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 480 V, T <sub>C</sub> = 125°C			10	μΑ
I <sub>GSSF</sub>	Gate-Body Leakage Current, Forward	V <sub>GS</sub> = 30 V, V <sub>DS</sub> = 0 V			100	nA
I <sub>GSSR</sub>	Gate-Body Leakage Current, Reverse	$V_{GS} = -30 \text{ V}, V_{DS} = 0 \text{ V}$			-100	nA
On Cha	aracteristics					
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2.0		4.0	V
R <sub>DS(on)</sub>	Static Drain-Source On-Resistance	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 3.75 A		1.0	1.2	Ω
9 <sub>FS</sub>	Forward Transconductance	$V_{DS} = 40 \text{ V}, I_D = 3.75 \text{ A}$		8.7		S
Dynam	ic Characteristics					
C <sub>iss</sub>	Input Capacitance	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V},$ f = 1.0 MHz		965	1255	рF
Coss	Output Capacitance			105	135	pF
C <sub>rss</sub>	Reverse Transfer Capacitance			12	16	pF
Switchi	ing Characteristics					
t <sub>d(on)</sub>	Turn-On Delay Time	$V_{DD} = 300 \text{ V}, I_D = 7.5\text{A},$		16.5	45	ns
t <sub>r</sub>	Turn-On Rise Time	$R_G = 25 \Omega$		60.5	130	ns
t <sub>d(off)</sub>	Turn-Off Delay Time			81	170	ns
t <sub>f</sub>	Turn-Off Fall Time	(Note 4)		64.5	140	ns
Qg	Total Gate Charge	V <sub>DS</sub> = 480 V, I <sub>D</sub> = 7.5A,		28	36	nC
Q <sub>gs</sub>	Gate-Source Charge	V <sub>GS</sub> = 10 V		4.5		nC
_		+ ~~ +			1	

### **Drain-Source Diode Characteristics and Maximum Ratings**

		•				
I <sub>S</sub>	Maximum Continuous Drain-Source Diode Forward Current				7.5	Α
I <sub>SM</sub>	Maximum Pulsed Drain-Source Diode F	orward Current			30	Α
V <sub>SD</sub>	Drain-Source Diode Forward Voltage	$V_{GS} = 0 \text{ V}, I_{S} = 7.5 \text{ A}$			1.4	V
t <sub>rr</sub>	Reverse Recovery Time	$V_{GS} = 0 \text{ V, } I_{S} = 7.5 \text{ A,}$		365		ns
Q <sub>rr</sub>	Reverse Recovery Charge	$dI_F / dt = 100 A/\mu s$		3.4		μС

 $Q_{gd}$ 

Gate-Drain Charge

nC

12

**Notes:** 1. Repetitive rating: pulse-width limited by maximum junction temperature. 2.L = 7.3 mH,  $I_{AS}$  = 7.5 A,  $V_{DD}$  = 50 V,  $R_{G}$  = 25  $\Omega$ , starting  $T_{J}$  = 25°C. 3. $I_{SD} \le 7.5$  A, di/dt  $\le 200$  A/ $\mu$ s,  $V_{DD} \le BV_{DSS}$ , starting  $T_{J}$  = 25°C. 4. Essentially independent of operating temperature.

### **Typical Characteristics**

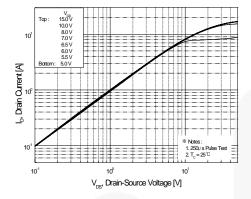


Figure 1. On-Region Characteristics

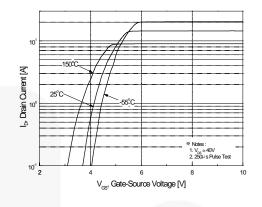


Figure 2. Transfer Characteristics

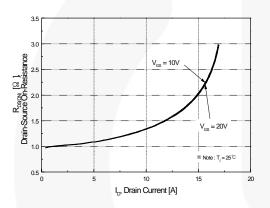


Figure 3. On-Resistance Variation vs Drain Current and Gate Voltage

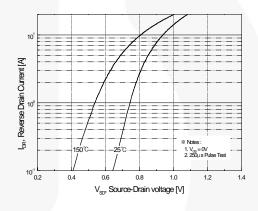


Figure 4. Body Diode Forward Voltage Variation with Source Current and Temperature

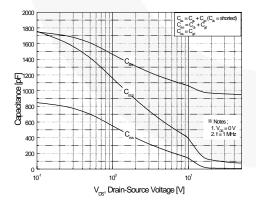


Figure 5. Capacitance Characteristics

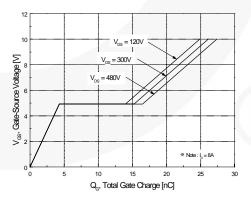


Figure 6. Gate Charge Characteristics

### Typical Characteristics (Continued)

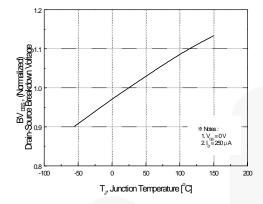
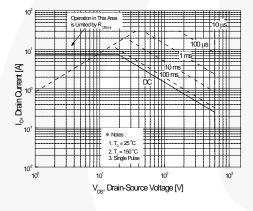


Figure 7. Breakdown Voltage Variation vs Temperature

Figure 8. On-Resistance Variation vs Temperature



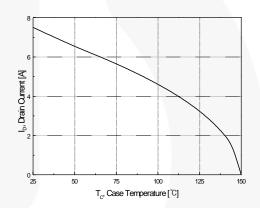


Figure 9. Maximum Safe Operating Area

Figure 10. Maximum Drain Current vs Case Temperature

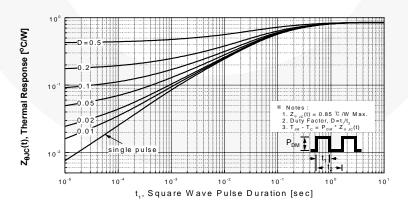


Figure 11. Transient Thermal Response Curve

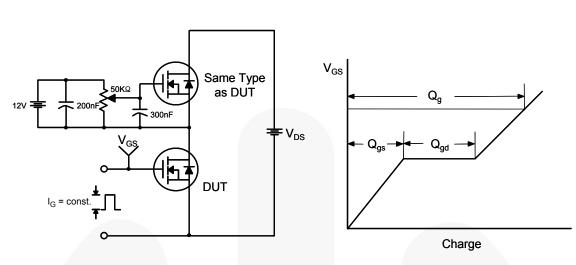


Figure 12. Gate Charge Test Circuit & Waveform

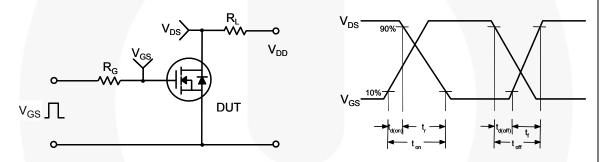


Figure 13. Resistive Switching Test Circuit & Waveforms

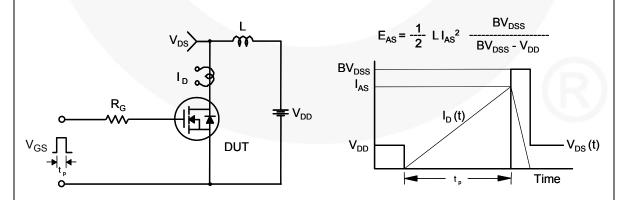
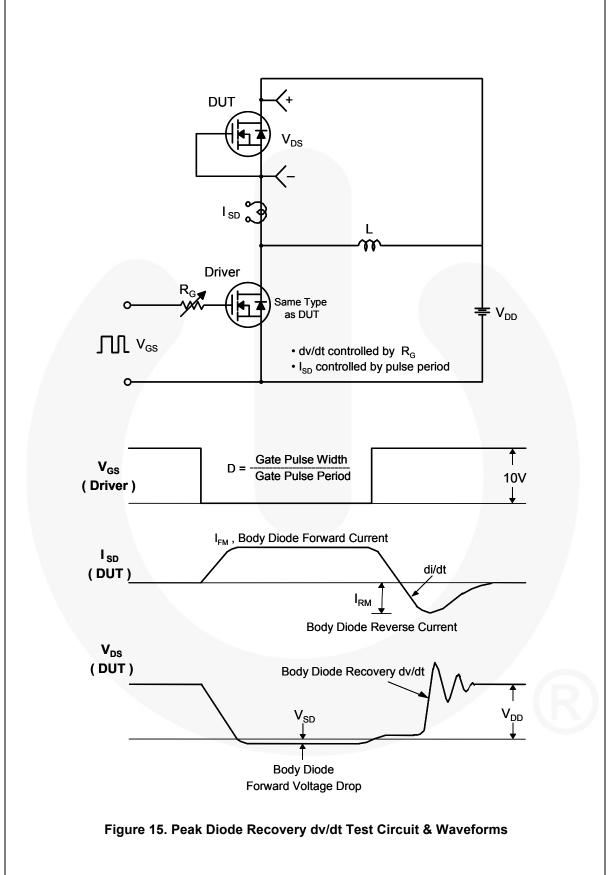


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms



### **Mechanical Dimensions**

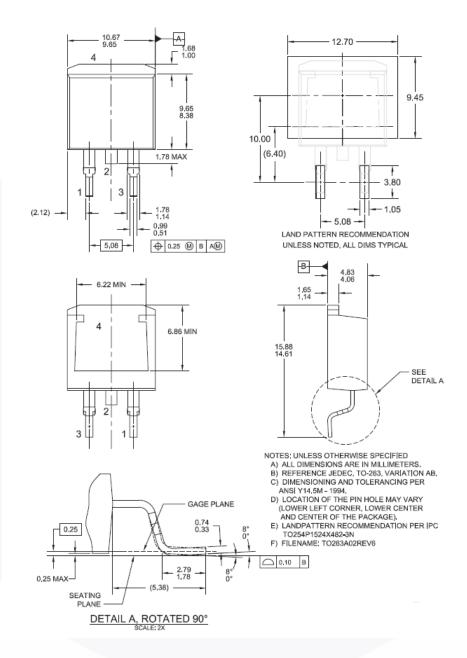


Figure 16. TO263 (D<sup>2</sup>PAK), Molded, 2-Lead, Surface Mount

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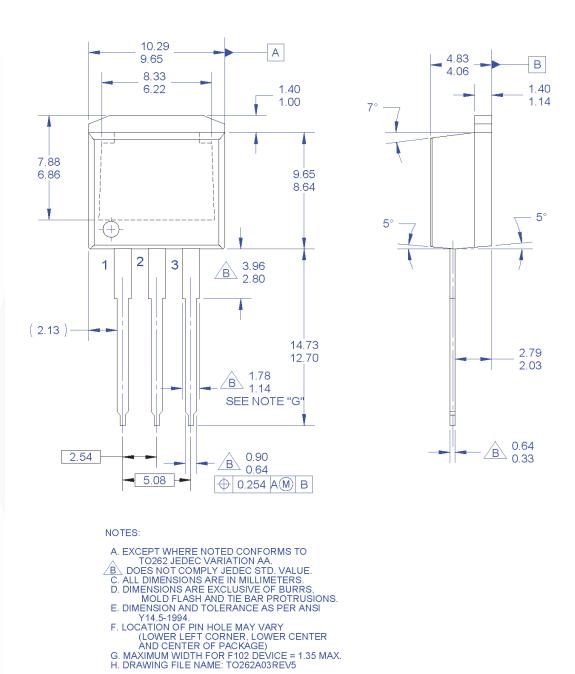


Figure 17. TO262 (I<sup>2</sup>PAK), Molded, 3-Lead, Jedec Variation AA

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